Resonantly pumped optical pumping injection cavity lasers

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An optical parametric oscillator is tuned to the resonance wavelength of the etalon in an optical pumping injection cavity (OPIC) laser with a type-II “W” active region, thereby minimizing the threshold pump intensity and maximizing the output slope efficiency. Previous OPIC experiments employed fixed-wavelength sources with only limited tuning available by adjusting the incident angle. Low threshold pump intensities of 330 W/cm² at 100 K and 14 kW/cm² at 300 K (where the output wavelength is 3200 nm) were achieved. The energy conversion efficiency is found to decrease by over a factor of 100 when the pump wavelength is tuned from the resonance condition (1822 nm at 300 K) to only slightly off resonance (e.g., 1808 nm). © 2004 American Institute of Physics. [DOI: 10.1063/1.1801164]

INTRODUCTION

Quantum well (QW) lasers based on the type-II antimonide heterostructure system have made significant progress toward efficient, room-temperature operation in the midinfrared. 1 While electrical injection 2,3 ultimately will be ideal, the optically pumped devices have thus far produced much higher powers than their diode counterparts. 4–8 To ensure the efficient injection of carriers, these optically pumped lasers have employed two main approaches to maximize the absorption of pump photons in the active region. In the integrated absorber (IA) method first introduced for the type-II antimonides by the Massachusetts Institute of Technology Lincoln Laboratory 9–11 and further developed at the Air Force Research Laboratory, 6–8 thick GaInAsSb layers that absorb at \( \lambda_{\text{pump}} = 1800 \) nm surround each active type-II “W” period. The photons absorbed in these layers quickly diffuse to the active QWs.

Another successful approach has been the optical pumping injection cavity (OPIC) laser, 12,13 in which the active region is enclosed between two GaSb/AlAsSb-distributed Bragg reflector (DBR) mirrors that induce multiple passes of the pump beam. A schematic is shown in Fig. 1. Tuning the etalon resonance to the pump wavelength (but not to the mid-IR emission wavelength because vertical-cavity lasing is not desired) substantially enhances the net pump absorption efficiency despite a weak absorption for each single pass. The threshold pump intensity is simultaneously reduced, since each QW has multiple opportunities to absorb a given pump photon. The OPIC suppresses internal losses as well, because fewer active QWs are needed to efficiently absorb the pump. This results in less free-carrier absorption of the mid-IR lasing beam by photo-injected carriers. 7,13 It should be further noted with a view toward future work that if the barriers between the QW periods are replaced by GaInAsSb absorbing layers, the hybrid OPIC/IA geometry would combine the advantages of both and allow a further reduction in the number of active QWs.

The first OPIC lasers to be investigated 12,13 were designed for pumping by a Q-switched Ho:YAG laser emitting at 2100 nm. Whereas the cavity resonance wavelength (\( \lambda_{\text{cav}} \)) for normal incidence, as determined from the transmittance spectrum, occurred at a slightly longer wavelength (e.g.,...
The OPIC sample was grown by molecular beam epitaxy on an \( n \)-GaSb substrate. The strain-compensated type-II W active region (10 periods of 21 Å InAs/34 Å GaSb/21 Å InAs/40 Å AlSb) was surrounded on both sides by 100 Å AlAs\(_{0.08}\)Sb\(_{0.92}\) hole-blocking layers and 5213 Å GaSb spacer layers. The top (10 period) and bottom (18.5 period) DBRs contained alternating layers of 1758 Å AlAs\(_{0.08}\)Sb\(_{0.92}\) and 1451 Å GaSb.

Figure 2 illustrates the normal-incidence reflectance spectrum as measured by a Fourier transform infrared (FTIR) spectrometer (solid curve). Note that the apparent maximum reflectivity in the plateau region exceeds unity slightly \((\approx 1.04)\), probably because the reflection of the reference beam was only \( \approx 96\% \). For comparison, the dashed curve shows the results of a simulation, whose only parameter is to adjust all the layer thicknesses by the same constant factor so as to bring the resonance wavelength (indicated by the notch in the plateau) into approximate agreement with the experimental \( \lambda_{\text{cav}} \). The theory shows more structure on the short-wavelength side of the plateau because the onset of absorption within the GaSb layers is not included. While this structure was designed for excitation by a quasi-cw diode laser array with \( \lambda_{\text{pump}} = 850 \) nm at 300 K, the cavity resonance occurs at 1790–1830 nm (varying slightly with the position on the wafer). Thus, the angle tuning could never bring the OPIC into a resonance with the diode array wave- length, whereas the OPO source at normal incidence easily tunes to \( \lambda_{\text{cav}} \) for any temperature of interest. Because the reflectance and lasing samples were taken from different portions of the wafer, the value of \( \lambda_{\text{cav}} = 1830 \) nm, indicated by the spectrum in Fig. 2, is \( \approx 9 \) nm longer than that determined from the lasing experiments discussed in the succeeding paragraphs. We also point out that even at resonance, the reflectance never falls below 75\%. This limits the maximum energy conversion efficiency because it places an upper bound of 25\% on the fraction of the pump beam absorbed within the active quantum wells. More optimized designs can yield absorbed fractions exceeding 80\%.

The Spectra-Physics Quanta-Ray MOPO-PO produces wavelengths tunable from the visible to the slightly beyond 2 \( \mu \)m when its BBO crystal is pumped at 10 Hz by the third harmonic (355 nm) from a Spectra-Physics Quanta-Ray Pro250 Nd:YAG laser. The OPO idler output pulses vary in length from 3.85 to 3.42 ns as the pump wavelength is increased from 1770 to 1840 nm. The wavelengths of 1770–1840 nm span the resonances over the full temperature range and hence are of greatest interest in this work. Because both the pulse length of the pump laser and the radiative lifetime in the mid-IR laser are much shorter than the detector response time, the detector functions as an energy integrator in this experiment. For that reason, we will report energy conversion efficiencies rather than power conversion efficiencies as in most previous work on optically pumped mid-IR lasers (for which the pulse length was generally longer than the detector response time). The intensity of the pump beam was controlled by rotating a polarizing cube and was measured with a LaserProbe ratiometer. The idler beam was shaped using cylindrical lenses to control its length and width, which for these experiments resulted in a pump stripe width of 180 \( \mu \)m (full width at half maximum). The sample was cleaved to a cavity length of 1.22 mm and mounted with uncoated facets to the cold finger of an Advanced Research Systems Helitrans cryostat using GE varnish.

The output power was measured using a Judson liquid-nitrogen-cooled HgCdTe detector. The peak output power as a function of the peak pump power was measured at and near the temperature condition \((\lambda_{\text{pump}} = \lambda_{\text{cav}})\) for temperature ranging from 77 to 350 K, the maximum heater temperature. Spectra were measured at each temperature utilizing an Instruments S.A. TRIAX 550 triple-grating, dual-axis spectrometer. The emission from the OPIC laser was at wavelengths ranging from 2.9 \( \mu \)m at 77 K to 3.2 \( \mu \)m at 350 K.

**DISCUSSION**

Output energy per pulse versus pump energy density per pulse for a range of pump wavelengths is plotted in Fig. 3. For the shorter-wavelength side of the resonance only, light-light curves are shown for \( T = 100 \) and 300 K. Longer wavelengths on the far side of the resonance are omitted for clarity because they display very similar behavior. The plots confirm that both the threshold pump energy density (and correspondingly, the threshold pump intensity) and the slope...
efficiency depend quite strongly on the pump wavelength. The light-light “fans” shown in Fig. 3 are representative of the behavior at all temperatures.

Figure 4 illustrates further that when the pump wavelength is varied, the threshold pump intensity (open points, left axis) has a minimum and the energy conversion efficiency per facet (filled points, right axis) has a maximum at the cavity resonance, with the spectral variations on each side of the resonance being roughly symmetric. For example, when $\lambda_{\text{pump}}$ is tuned to only 13 nm below the resonance wavelength at 100 K (i.e., 1772 nm versus 1785 nm), the threshold increases by a factor of 10 and the efficiency decreases by nearly a factor of 30. At room temperature, the transmission 15 nm away from resonance (see Fig. 2) is a factor of 12–13 less than at resonance, whereas the efficiency is over 100 times smaller.

There is a strong correlation between the width of the reflectance notch in Fig. 2 and the width of the efficiency peak in Fig. 4(b) because both directly depend on the cavity resonance. The pump absorbance, which dominates the magnitude of the efficiency, is nearly equal to $1 - R$ because there is very little transmission when $\lambda = \lambda_{\text{cav}}$. This is confirmed by comparing the efficiency spectrum to the plot of $1 - R$ taken from the reflectivity data in Fig. 2. Here, the experimental reflectivity spectrum was shifted horizontally by 8.6 nm (to correct for the slight variation of $\lambda_{\text{cav}}$ with position across the wafer, $R$ was normalized to the maximum theoretical value (0.999), and the magnitude of $1 - R$ was then arbitrarily rescaled so as to align its maximum with that of the efficiency data.

The temperature dependence of the threshold pump intensity at resonance is shown in Fig. 5, where the inset plots $\lambda_{\text{cav}}$ versus temperature. The thresholds of 328 W/cm$^2$ at 100 K and 14 kW/cm$^2$ at 300 K are lower than those of most conventional optically pumped W devices, and the W-OPIC lasers from Refs. 12 and 13 had lower $I_{\text{th}}$ at all temperatures up to 300 K (Ref. 13) because their pump absorbance at resonance was greater.

Energy conversion efficiency per single facet versus temperature is shown in Fig. 6. The efficiencies are determined from the slope of the light-light curves at the corresponding resonant pump wavelength (see inset, Fig. 5). The theoretical value of 0.999. Finally, the magnitude of $1 - R$ was arbitrarily rescaled so as to match its peak height to that of the efficiency data in the figure. We find that the widths of the $1 - R$ and efficiency spectra are nearly identical. The more rapid decay in the tail region of the efficiency curve may be associated in part with the difficulty in obtaining an accurate slope when very intense pumping is required because the wavelength is relatively far from resonance (see Fig. 3(b)).
efficiency at 125 K is 1.25%, and the falloff with temperature is similar to that observed in the earlier OPIC and non-OPIC devices, reaching approximately 0.22% at 300 K. The efficiencies at the lowest temperatures are not as high as expected when measured with respect to values above 150 K. At the lowest temperatures, the pump pulse lengths may become shorter than the radiative lifetimes in the OPIC laser.

CONCLUSIONS

In conclusion, varying the idler wavelength from an OPO pump source made it possible to tune into the OPIC resonances for normal-incidence excitation at any temperature. This greatly facilitates the evaluation of device performance under optimal conditions. As expected, the efficiency displays a sharp maximum and the threshold a distinct minimum when the OPIC laser is pumped at the resonant wavelength for any given temperature. The resonant efficiency exceeds efficiencies only ~13 nm off resonance by a factor of approximately 30 at 100 K, while thresholds are at least an order of magnitude higher away from the resonant pump wavelength. The spectral width of the efficiency maximum near the resonance was found to match almost exactly that of the peak in $1 - R$. Operation of these lasers was achieved to 350 K and is expected to higher temperatures.

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